

# TPD12S016 具有 I<sup>2</sup>C 电平转换缓冲器、12 通道 ESD 保护和限流负载开关的 HDMI 配套芯片

## 1 特性

- 符合 HDMI 兼容性测试，无需任何外部组件
- IEC 61000-4-2 静电放电 (ESD) 保护
  - $\pm 8kV$  接触放电
- 支持高清多媒体接口 (HDMI) 1.4 数据速率
- 与 D 类和 C 类引脚映射相匹配
- 采用超低差分电容匹配 (0.05pF) 为四个差分对提供 8 通道 ESD 保护
- HDMI 5V\_OUT 引脚上具有 55mA 电流限制的片上负载开关
- 自动方向感应 I<sup>2</sup>C 电平转换器，采用单触发电路驱动长 HDMI 电缆 (750pF 负载)
- HDMI 连接器侧端口具有反向驱动保护
- 遵照 HDMI 规范集成上拉和下拉电阻
- 采用节约空间的 24 引脚 RKT 封装和 24 引脚 TSSOP 封装

## 2 应用范围

- 手机
- 电子书
- 便携式媒体播放器
- 机顶盒

## 3 说明

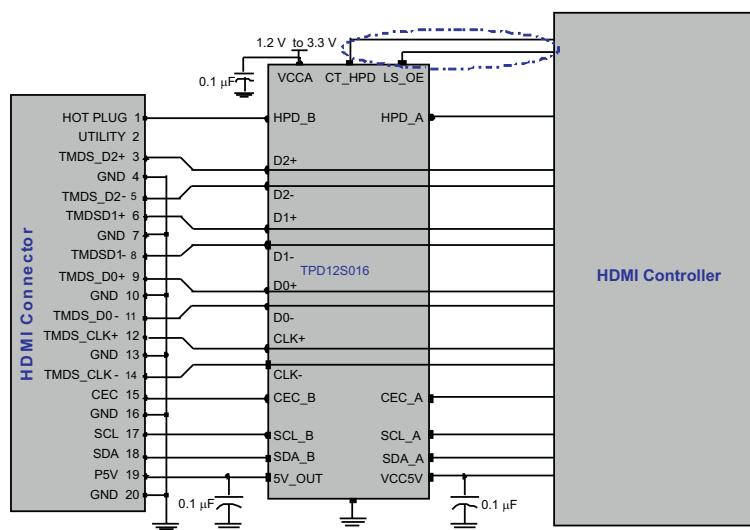
TPD12S016 是一款单芯片高清多媒体接口 (HDMI) 器件，具有自动方向感应 I<sup>2</sup>C 电压电平转换缓冲器、负载开关和集成式低电容高速静电放电 (ESD) 瞬态电压抑制 (TVS) 保护二极管。通过 55mA 限流 5V 输出 (5V\_OUT) 为 HDMI 电力线供电。5V\_OUT 和热插拔检测 (HPD) 电路的控制与 LS\_OE 控制信号无关，其通过 CT\_HPD 引脚进行控制，使得在启用 HDMI 链路前即可激活检测方案 (5V\_OUT 和 HPD)。SDA、SCL 和 CEC 线路上拉到 A 侧的 V<sub>CCA</sub>。在 B 侧，CEC\_B 引脚上拉到内部 3.3V 电源轨，SCL\_B 和 SDA\_B 均上拉到 5V 电源轨 (5V\_OUT)。SCL 和 SDA 引脚满足 I<sup>2</sup>C 规范，可驱动高达 750pF 电容负载，超出了 HDMI 1.4 规范。HPD\_B 端口配有毛刺脉冲滤波器，可在插入 HDMI 连接器时避免由插座跳起引起的错误检测。TPD12S016 的 5V\_OUT 引脚具有反向电流阻断功能。系统断电时，SCL\_B、SDA\_B 和 CEC\_B 引脚也具有反向电流阻断功能。

### 器件信息<sup>(1)</sup>

器件型号	封装	封装尺寸 (标称值)
TPD12S016	QFN (24)	4.00mm x 2.00mm
	TSSOP (24)	7.80mm x 6.40mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

简化电路原理图



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

## 目录

<b>1</b>	特性 .....	1	7.3	Feature Description .....	14
<b>2</b>	应用范围 .....	1	7.4	Device Functional Modes .....	16
<b>3</b>	说明 .....	1	<b>8</b>	<b>Application and Implementation</b> .....	17
<b>4</b>	修订历史记录 .....	2	8.1	Application Information .....	17
<b>5</b>	<b>Pin Configuration and Functions</b> .....	3	8.2	Typical Application .....	17
<b>6</b>	<b>Specifications</b> .....	4	<b>9</b>	<b>Power Supply Recommendations</b> .....	20
6.1	Absolute Maximum Ratings .....	4	<b>10</b>	<b>Layout</b> .....	20
6.2	ESD Ratings .....	4	10.1	Layout Guidelines .....	20
6.3	Recommended Operating Conditions .....	5	10.2	Layout Examples .....	20
6.4	Thermal Information .....	5	<b>11</b>	器件和文档支持 .....	22
6.5	Electrical Characteristics .....	6	11.1	社区资源 .....	22
6.6	Switching Characteristics .....	8	11.2	商标 .....	22
6.7	Typical Characteristics .....	11	11.3	静电放电警告 .....	22
<b>7</b>	<b>Detailed Description</b> .....	13	11.4	Glossary .....	22
7.1	Overview .....	13	<b>12</b>	<b>机械、封装和可订购信息</b> .....	22
7.2	Functional Block Diagram .....	13			

**4 修订历史记录**

注：之前版本的页码可能与当前版本有所不同。

<b>Changes from Revision E (December 2014) to Revision F</b>		<b>Page</b>
• Added test condition frequency to capacitance .....		6
• Added test condition frequency to capacitance .....		7
• 已添加 <a href="#">社区资源</a> .....		22

<b>Changes from Revision D (August 2013) to Revision E</b>		<b>Page</b>
• 已添加 处理额定值表，特性 描述部分，器件功能模式，应用和实施部分，电源相关建议部分，布局部分，器件和文档 支持部分以及机械、封装和可订购信息部分 .....		1

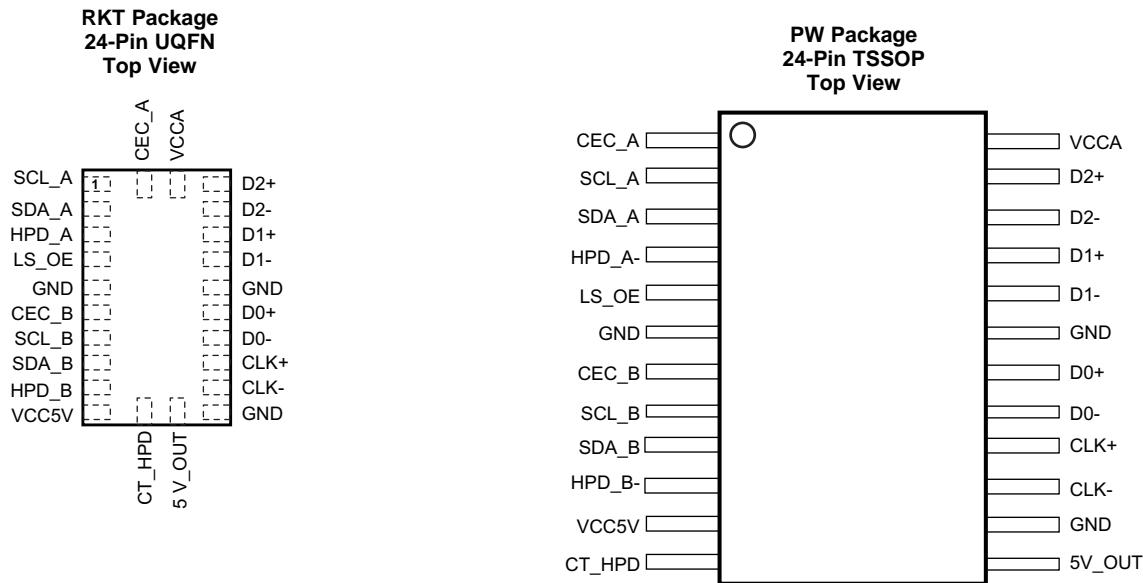
<b>Changes from Original (January 2013) to Revision A</b>		<b>Page</b>
• Added Eye Diagram Using EVM Without TPD12S016 for the TMDS Lines at 1080p, 340MHz Pixel Clock, 3.4Gbps.....	18	18
• Added Eye Diagram Using EVM with TPD12S016 for the TMDS Lines at 1080p, 340MHz Pixel Clock, 3.4Gbps.....		18

<b>Changes from Revision A (February 2013) to Revision B</b>		<b>Page</b>
• Added PW and RKT packages values for IO capacitance .....		6
• Added LOAD SWITCH $I_{LEAKAGE\_REVERSE}$ vs $V_{5V\_OUT}$ graph .....		11
• Updated Circuit Schematic Diagram .....		13

<b>Changes from Revision B (February 2013) to Revision C</b>		<b>Page</b>
• Updated table formatting .....		6

<b>Changes from Revision C (August 2013) to Revision D</b>		<b>Page</b>
• Updated power savings options table.....		16

## 5 Pin Configuration and Functions



### Pin Functions

PIN		TYPE	DESCRIPTION	
NAME	RKT		PW	
D-, D+	16, 17, 19 to 22	17, 18, 20 to 23	IO	HDMI TMDS data. Connect to HDMI controller and HDMI connector directly
CLK+, CLK-	14, 15	15, 16	IO	HDMI TMDS clock. Connect to HDMI controller and HDMI connector directly
HPD_A	3	4	O	Hot plug detect output referenced to VCCA. Connect to HDMI controller hot plug detect input pin
HPD_B	9	10	I	Hot plug detect input. Connect directly to HDMI connector hot plug detect pin
CEC_A	24	1	IO	HDMI controller side CEC signal pin referenced to VCCA. Connect to HDMI controller
CEC_B	6	7	IO	HDMI connector side CEC signal pin referenced to internal 3.3-V supply. Connect to HDMI connector CEC pin
SCL_A	1	2	IO	HDMI controller side SCL signal pin referenced to VCCA. Connect to HDMI controller
SCL_B	7	8	IO	HDMI connector side SCL signal pin referenced to 5V_OUT supply. Connect to HDMI connector SCL pin
SDA_A	2	3	IO	HDMI controller side SDA signal pin referenced to VCCA. Connect to HDMI controller
SDA_B	8	9	IO	HDMI connector side SDA signal pin referenced to 5V_OUT supply. Connect to HDMI connector SDA pin
LS_OE	4	5	I	Disables the Level shifters when OE = L. The OE pin is referenced to VCCA
CT_HPD	11	12	I	Disables the load switch and HPD_B when CT_HPD = L. The CT_HPD is referenced to VCCA
VCC5V	10	11	PWR	Internal 5-V supply (input to the load switch)
VCCA	23	24	PWR	Internal PCB low voltage supply (same as the HDMI controller chip supply)
5V_OUT	12	13	O	External 5-V supply (output of the load switch)
GND	5, 13, 18	6, 14, 19	GND	Connect to system ground plane

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CCA}$	Supply voltage		-0.3	4.0	V
$V_{CC5V}$	Supply voltage		-0.3	6.0	V
$V_I$	Input voltage <sup>(1)</sup>	SCL_A, SDA_A, CEC_A	-0.3	4.0	V
		SCL_B, SDA_B, CEC_B	-0.3	6.0	
		CT_HPD, LS_OE	-0.3	4.0	
		D, CLK	-0.3	6.0	
$V_O$	Voltage applied to any output in the high-impedance or power-off state <sup>(1)</sup>	SCL_A, SDA_A, CEC_A, CT_HPD, LS_OE	-0.3	4.0	V
		SCL_B, SDA_B, CEC_B	-0.3	6.0	
$V_O$	Voltage applied to any output in the high or low state <sup>(1)(2)</sup>	SCL_A, SDA_A, CEC_A, CT_HPD, LS_OE	-0.3	$V_{CCA} + 0.5$	V
		SCL_B, SDA_B, CEC_B	-0.3	$5V_{OUT} + 0.5$	
$I_{IK}$	Input clamp current	$V_I < 0$		-50	mA
$I_{OK}$	Output clamp current	$V_O < 0$		-50	mA
	Continuous current through $5V_{OUT}$ , or GND			$\pm 100$	mA
$T_{stg}$	Storage temperature		-65	150	°C

- (1) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.  
(2) The package thermal impedance is calculated in accordance with JESD 51-7.

### 6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001	LS_OE, CT_HPD, SCL_A, SDA_A, CEC_A, HPD_A, $V_{CCA}$	$\pm 2000$
			Dx, CLKx, SCL_B, SDA_B, CEC_B, HPD_B, $5V_{OUT}$	$\pm 15000$
		Charged-device model (CDM), per JEDEC specification JESD22-C101		$\pm 1000$
		IEC 61000-4-2 Contact Discharge	Dx, CLKx, SCL_B, SDA_B, CEC_B, HPD_B, $5V_{OUT}$	$\pm 8000$

### 6.3 Recommended Operating Conditions

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
$V_{CCA}$ Supply voltage			1.1		3.6	V
$V_{CC5V}$ Supply voltage			4.5		5.5	V
$V_{IH}$ High-level input voltage	SCL_A, SDA_A	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	$0.7 \times V_{CCA}$		$V_{CCA}$	V
	CEC_A	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	$0.7 \times V_{CCA}$		$V_{CCA}$	V
	CT_HPD, LS_OE	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	1.0		$V_{CCA}$	V
	SCL_B, SDA_B	$5V_{\_OUT} = 5.0\text{ V}$	$0.7 \times 5V_{\_OUT}$		$5V_{\_OUT}$	V
	CEC_B	$5V_{\_OUT} = 5.0\text{ V}$	$0.7 \times V_{3P3}^{(1)}$		$V_{3P3}$	
	HPD_B	$5V_{\_OUT} = 5.0\text{ V}$	2.0		$5V_{\_OUT}$	
$V_{IL}$ Low-level input voltage	SCL_A, SDA_A	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	-0.5	$0.082 \times V_{CCA}$		V
	CEC_A	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	-0.5	$0.082 \times V_{CCA}$		V
	CT_HPD, LS_OE	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	-0.5		0.4	V
	SCL_B, SDA_B	$5V_{\_OUT} = 5.0\text{ V}$	-0.5	$0.3 \times 5V_{\_OUT}$		V
	CEC_B	$5V_{\_OUT} = 5.0\text{ V}$	-0.5	$0.3 \times V_{3P3}$		V
	HPD_B	$5V_{\_OUT} = 5.0\text{ V}$	0		0.8	V
$V_{ILC}$ (contention) Low-level input voltage	SCL_A, SDA_A, CEC_A	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$	-0.5	$0.065 \times V_{CCA}$		V
$V_{OL} - V_{ILC}$ Delta between $V_{OL}$ and $V_{ILC}$	SCL_A, SDA_A, CEC_A	$V_{CCA} = 1.1\text{ V to }3.6\text{ V}$		$0.1 \times V_{CCA}$		mV
$T_A$ Operating free-air temperature			-40		85	°C

- (1) The  $V_{3P3}$  is an internal 3.3V power supply node. The  $V_{3P3}$  is generated from the 5V supply pin through the on-chip LDO.

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>	TPD12S016		UNIT
	RKT (UQFN)	PW (TSSOP)	
	24 PINS	24 PINS	
$R_{\theta JA}$ Junction-to-ambient thermal resistance	77.9	88.9	°C/W
$R_{\theta JC(\text{top})}$ Junction-to-case (top) thermal resistance	24.0	26.5	°C/W
$R_{\theta JB}$ Junction-to-board thermal resistance	29.3	43.5	°C/W
$\Psi_{JT}$ Junction-to-top characterization parameter	0.5	1.1	°C/W
$\Psi_{JB}$ Junction-to-board characterization parameter	29.3	43.0	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
<b>HIGH SPEED ESD LINES: D<sub>x</sub>, CLK<sub>x</sub></b>							
I <sub>IO</sub>	Current through ESD clamp ports	V <sub>CCA</sub> = 3.3 V, V <sub>CCSV</sub> = 5.0 V, V <sub>IO</sub> = 3.3 V	D, CLK		0.01	0.5	μA
V <sub>DL</sub>	Diode forward voltage	I <sub>D</sub> = 8 mA	Lower clamp diode		0.8	1.0	V
R <sub>DYN</sub>	Dynamic resistance	I = 1 A	D, CLK		1		Ω
C <sub>IO</sub>	IO capacitance	PW Package	V <sub>CC</sub> = 5 V, V <sub>IO</sub> = 2.5 V f = 1 MHz	D, CLK	1.0		pF
		RKT Package			1.2		
ΔC <sub>IO_TMDS</sub>	Differential capacitance for the Dx+, Dx– lines	V <sub>CC</sub> = 5 V, V <sub>IO</sub> = 2.5 V f = 1 MHz	D, CLK		0.05		pF
V <sub>BR</sub>	Break-down voltage	I <sub>IO</sub> = 1 mA		6.5		9	V
<b>LOAD SWITCH V<sub>CCSV</sub>, 5V_OUT</b>							
I <sub>CCSV</sub>	Supply current at V <sub>CCSV</sub>	V <sub>CCSV</sub> = 5 V, 5V_OUT =Open, LS_OE = GND, CT_HPD = GND			1	45	μA
	Supply current at V <sub>CCSV</sub>	V <sub>CCSV</sub> = 5 V, 5V_OUT =Open, LS_OE = GND, CT_HPD = 3.3 V			4	50	μA
I <sub>SC</sub>	Short circuit current at 5V_OUT	V <sub>CCSV</sub> = 5 V, 5V_OUT = GND		100	150	200	mA
V <sub>DROP</sub>	5V_OUT output voltage drop	V <sub>CCSV</sub> = 5 V, I <sub>5V_OUT</sub> = 55 mA			35	50	mV
T <sub>ON</sub>	Turn on time, V <sub>CCSV</sub> to 5V_OUT	C <sub>LOAD</sub> = 0.1 μF, R <sub>LOAD</sub> = 500 Ω			77		μs
T <sub>OFF</sub>	Turn off time, V <sub>CCSV</sub> to 5V_OUT	C <sub>LOAD</sub> = 0.1 μF, R <sub>LOAD</sub> = 500 Ω			7.0		μs
T <sub>SHUT</sub>	Thermal Shutdown	Shutdown threshold, TRIP <sup>(1)</sup>			140		°C
		HYST <sup>(2)</sup>			12		
<b>VOLTAGE LEVEL SHIFTER – SCL, SDA LINES (x_A AND x_B PORTS)</b>							
V <sub>OHA</sub>	I <sub>OH</sub> = -20 μA	V <sub>I</sub> = V <sub>IH</sub>	V <sub>CCA</sub> = 1.1 V to 3.6 V	V <sub>CCA</sub> × 0.80			V
V <sub>OLA</sub>	I <sub>OL</sub> = 20 μA	V <sub>I</sub> = V <sub>IL</sub>	V <sub>CCA</sub> = 1.1 V to 3.6 V	V <sub>CCA</sub> × 0.17			V
V <sub>OHB</sub>	I <sub>OH</sub> = -20 μA	V <sub>I</sub> = V <sub>IH</sub>		5VOUT × 0.90			V
V <sub>OLB</sub>	I <sub>OL</sub> = 3 mA	V <sub>I</sub> = V <sub>IL</sub>		0.4			V
ΔV <sub>T</sub>	Hysteresis at the SDx_A (V <sub>T+</sub> – V <sub>T-</sub> )	V <sub>CCA</sub> = 1.1 V to 3.6 V		40			mV
ΔV <sub>T</sub>	Hysteresis at the SDx_B (V <sub>T+</sub> – V <sub>T-</sub> )	V <sub>CCA</sub> = 1.1 V to 3.6 V		400			mV
R <sub>P</sub>	(Internal pullup)	SCL_A, SDA_A	Pull-up connected to V <sub>CCA</sub> rail	10			kΩ
		SCL_B, SDA_B	Pull-up connected to 5-V rail	1.75			
I <sub>PULLUPAC</sub>	Transient boosted pullup current (rise-time accelerator)	SCL_B, SDA_B	Pull-up connected to 5-V rail	15			mA
I <sub>off</sub>	A port	V <sub>CCA</sub> = 0 V, V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6 V	V <sub>CCA</sub> = 0 V	±5			μA
	B port	5VOUT = 0 V, V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5 V	V <sub>CCA</sub> = 0 V to 3.6 V	±5			
I <sub>oz</sub>	B port	V <sub>O</sub> = V <sub>CCO</sub> or GND	V <sub>CCA</sub> = 1.1 V to 3.6 V	±5			μA
	A port	V <sub>I</sub> = V <sub>CCI</sub> or GND	V <sub>CCA</sub> = 1.1 V to 3.6 V	±5			

- (1) The TPD12S016 turns off after the device temperature reaches the TRIP temperature.
- (2) After the thermal shut-down circuit turns off the load switch, the switch turns on again after the device junction temperature cools down to a temperature equals to or less than TRIP-HYST.

## Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
<b>VOLTAGE LEVEL SHIFTER – CEC LINE (x_A AND x_B PORTS)</b>							
V <sub>OHA</sub>	I <sub>OH</sub> = -20 µA	V <sub>I</sub> = V <sub>IH</sub>	V <sub>CCA</sub> = 1.1 V to 3.6 V	V <sub>CCA</sub> × 0.80			V
V <sub>OLA</sub>	I <sub>OL</sub> = 20 µA	V <sub>I</sub> = V <sub>IL</sub>	V <sub>CCA</sub> = 1.1 V to 3.6 V	V <sub>CCA</sub> × 0.17			V
V <sub>OHB</sub>	I <sub>OH</sub> = -20 µA	V <sub>I</sub> = V <sub>IH</sub>		V <sub>3P3</sub> × 0.80			V
V <sub>OLB</sub>	I <sub>OL</sub> = 3 mA	V <sub>I</sub> = V <sub>IL</sub>				0.4	V
ΔV <sub>T</sub>	Hysteresis at the Sxx_A (V <sub>T+</sub> - V <sub>T-</sub> )	V <sub>CCA</sub> = 1.1 V to 3.6 V			40		mV
ΔV <sub>T</sub>	Hysteresis at the Sxx_B (V <sub>T+</sub> - V <sub>T-</sub> )	V <sub>CCA</sub> = 1.1 V to 3.6 V			300		mV
R <sub>PU</sub> (Internal pullup)	CEC_A	Pull-up connected to V <sub>CCA</sub> rail			10		kΩ
	CEC_B	Pull-up connected to 3.3 V rail			22	26	30
I <sub>off</sub>	A port	V <sub>CCA</sub> = 0 V, V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6 V	V <sub>CCA</sub> = 0 V			±5	µA
	B port	5VOUT = 0 V, V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5 V	V <sub>CCA</sub> = 0 V to 3.6 V			±1.8	
I <sub>OZ</sub>	B port	V <sub>O</sub> = V <sub>CCO</sub> or GND	V <sub>CCA</sub> = 1.1 V to 3.6 V			±5	µA
	A port	V <sub>I</sub> = V <sub>CCI</sub> or GND	V <sub>CCA</sub> = 1.1 V to 3.6 V			±5	
<b>VOLTAGE LEVEL SHIFTER – HPD LINE (x_A AND x_B PORTS)</b>							
V <sub>OHA</sub>	I <sub>OH</sub> = -3 mA	V <sub>I</sub> = V <sub>IH</sub>	V <sub>CCA</sub> = 1.1 V to 3.6 V	V <sub>CCA</sub> × 0.07			V
V <sub>OLA</sub>	I <sub>OL</sub> = 3 mA	V <sub>I</sub> = V <sub>IL</sub>	V <sub>CCA</sub> = 1.1 V to 3.6 V			0.4	V
ΔV <sub>T</sub>	Hysteresis (V <sub>T+</sub> - V <sub>T-</sub> )	V <sub>CCA</sub> = 1.1 V to 3.6 V			400		mV
R <sub>PD</sub>	(Internal pulldown resistor)	HPD_B	Pull-down connected to GND		11		kΩ
I <sub>off</sub>	A port	V <sub>O</sub> = V <sub>CCO</sub> or GND	V <sub>CCA</sub> = 0 V			±5	µA
I <sub>OZ</sub>	A port	V <sub>I</sub> = V <sub>CCI</sub> or GND	V <sub>CCA</sub> = 3.6 V			±5	µA
<b>LS_OE, CT_CP_HPD</b>							
I <sub>I</sub>	V <sub>I</sub> = V <sub>CCA</sub> or GND	V <sub>CCA</sub> = 1.1 V to 3.6 V				±12	µA
<b>I/O CAPACITANCES</b>							
C <sub>I</sub>	Control inputs	V <sub>I</sub> = 1.89 V or GND	V <sub>CCA</sub> = 1.1 to 3.6 V; f = 1 MHz		7.1		pF
C <sub>IO</sub>	A port	V <sub>O</sub> = 1.89 V or GND	V <sub>CCA</sub> = 1.1 to 3.6 V; f = 1 MHz		8.3		pF
	B port	V <sub>O</sub> = 5.0 V or GND	V <sub>5VOUT</sub> = 5.0 V; f = 1 MHz		15		pF

## 6.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		PINS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
C <sub>L</sub>	Bus load capacitance (B side)					750	
	Bus load capacitance (A side)					15	pF
<b>VOLTAGE LEVEL SHIFTER – SCL, SDA LINES (x_A And x_B PORTS) V<sub>CCA</sub> = 1.2 V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	SCL/SDA channels enabled	310			
		B to A		420			ns
t <sub>PLH</sub>	Propagation delay	A to B		510			
		B to A		427			ns
t <sub>FALL</sub>	A Port fall time	A-Port		334			
	B Port fall time	B-Port		225			ns
t <sub>RISE</sub>	A Port rise time	A-Port		315			
	B Port rise time	B-Port		415			ns
F <sub>(MAX)</sub>	Maximum switching frequency			400			kHz
<b>VOLTAGE LEVEL SHIFTER – CEC LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.2 V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	CEC channel enabled	385			
		B to A		526			ns
t <sub>PLH</sub>	Propagation delay	A to B		13.8			μs
		B to A		16.6			ns
t <sub>FALL</sub>	A Port fall time	A-Port		334			
	B Port fall time	B-Port		170			ns
t <sub>RISE</sub>	A Port rise time	A-Port		315			ns
	B Port rise time	B-Port		28			μs
<b>VOLTAGE LEVEL SHIFTER – HPD LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.2 V</b>							
t <sub>PHL</sub>	Propagation delay	B to A	HPD channel enabled	14.4			μs
t <sub>PLH</sub>	Propagation delay	B to A		9.2			μs
t <sub>FALL</sub>	A Port fall time	A-Port		2.1			ns
t <sub>RISE</sub>	A Port rise time	A-Port		2.1			ns
<b>VOLTAGE LEVEL SHIFTER – SCL, SDA LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.5 V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	SCL/SDA channels enabled	310			
		B to A		420			ns
t <sub>PLH</sub>	Propagation delay	A to B		410			ns
		B to A		425			ns
t <sub>FALL</sub>	A Port fall time	A-Port		250			ns
	B Port fall time	B-Port		225			ns
t <sub>RISE</sub>	A Port rise time	A-Port		315			ns
	B Port fall time	B-Port		415			ns
F <sub>(MAX)</sub>	Maximum switching frequency			400			kHz
<b>VOLTAGE LEVEL SHIFTER – CEC LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.5 V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	CEC channel enabled	380			
		B to A		420			ns
t <sub>PLH</sub>	Propagation delay	A to B		13.8			μs
		B to A		16.6			ns
t <sub>FALL</sub>	A Port fall time	A-Port		250			
	B Port fall time	B-Port		170			ns
t <sub>RISE</sub>	A Port rise time	A-Port		315			ns
	B Port rise time	B-Port		28			μs

## Switching Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

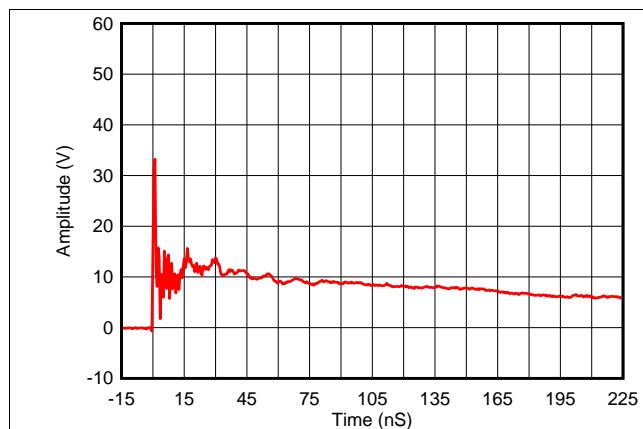
PARAMETER	PINS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>VOLTAGE LEVEL SHIFTER – HPD LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.5 V</b>						
t <sub>PHL</sub>	Propagation delay	B to A HPD channel enabled	14.4			μs
t <sub>PLH</sub>	Propagation delay		9.2			μs
t <sub>FALL</sub>	A Port fall time		1.8			ns
t <sub>Rise</sub>	A Port rise time		1.8			ns
<b>VOLTAGE LEVEL SHIFTER – SCL, SDA LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.8 V</b>						
t <sub>PHL</sub>	Propagation delay	A to B SCL/SDA channels enabled	300			ns
			350			ns
t <sub>PLH</sub>	Propagation delay		400			ns
			420			ns
t <sub>FALL</sub>	A Port fall time		210			ns
	B Port fall time		225			ns
t <sub>RISE</sub>	A Port rise time		315			ns
	B Port fall time		415			ns
F <sub>(MAX)</sub>	Maximum switching frequency		400			kHz
<b>VOLTAGE LEVEL SHIFTER – CEC LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.8 V</b>						
t <sub>PHL</sub>	Propagation delay	A to B CEC channel enabled	375			ns
			366			
t <sub>PLH</sub>	Propagation delay		13.8			μs
			16.6			ns
t <sub>FALL</sub>	A Port fall time		210			ns
	B Port fall time		170			
t <sub>RISE</sub>	A Port rise time		315			ns
	B Port rise time		28			μs
<b>VOLTAGE LEVEL SHIFTER – HPD LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 1.8 V</b>						
t <sub>PHL</sub>	Propagation delay	B to A HPD channels enabled	14.2			μs
t <sub>PLH</sub>	Propagation delay		9.2			μs
t <sub>FALL</sub>	A Port fall time		1.5			ns
t <sub>Rise</sub>	A Port rise time		1.5			ns
<b>VOLTAGE LEVEL SHIFTER – SCL, SDA LINES (x_A And x_B PORTS) V<sub>CCA</sub> = 2.5 V</b>						
t <sub>PHL</sub>	Propagation delay	A to B SCL/SDA channels enabled	300			ns
			400			
t <sub>PLH</sub>	Propagation delay		290			ns
			420			
t <sub>FALL</sub>	A Port fall time		170			kHz
	B Port fall time		225			
t <sub>RISE</sub>	A Port rise time		315			ns
	B Port fall time		415			
F <sub>(MAX)</sub>	Maximum switching frequency		400			kHz

## Switching Characteristics (continued)

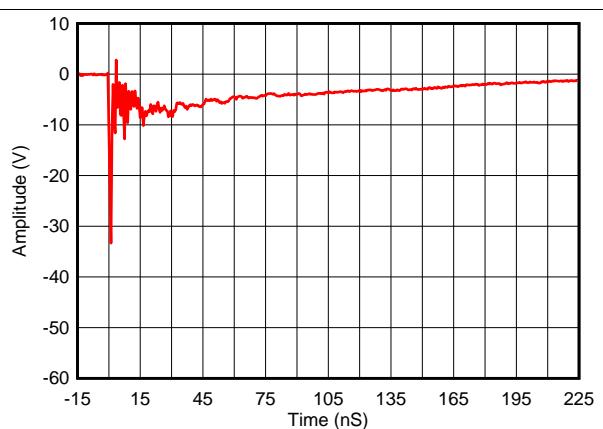
over operating free-air temperature range (unless otherwise noted)

PARAMETER		PINS	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>VOLTAGE LEVEL SHIFTER – CEC LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 2.5 V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	CEC channel enabled	375			ns
		B to A		305			
t <sub>PLH</sub>	Propagation delay	A to B		13.8			μs
		B to A		16.6			
t <sub>FALL</sub>	A Port fall time	A-Port		170			ns
	B Port fall time	B-Port		170			
t <sub>RISE</sub>	A Port rise time	A-Port		315			ns
	B Port rise time	B-Port		28			
<b>VOLTAGE LEVEL SHIFTER – HPD LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 2.5 V</b>							
t <sub>PHL</sub>	Propagation delay	B to A	HPD channel enabled	14.2			μs
t <sub>PLH</sub>	Propagation delay	B to A		9.2			
t <sub>FALL</sub>	A Port fall time	A-Port		1.2			ns
t <sub>RISE</sub>	A Port rise time	A-Port		1.2			
<b>VOLTAGE LEVEL SHIFTER – SCL, SDA LINES (x_A And x_B PORTS) V<sub>CCA</sub> = 3.3 V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	SCL/SDA channels enabled	300			ns
		B to A		400			
t <sub>PLH</sub>	Propagation delay	A to B		260			ns
		B to A		415			
t <sub>FALL</sub>	A Port fall time	A-Port		160			ns
	B Port fall time	B-Port		225			
t <sub>RISE</sub>	A Port rise time	A-Port		305			ns
	B Port fall time	B-Port		415			
F <sub>(MAX)</sub>	Maximum switching frequency			400			kHz
<b>VOLTAGE LEVEL SHIFTER – CEC LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 3.3V</b>							
t <sub>PHL</sub>	Propagation delay	A to B	CEC channel enabled	375			ns
		B to A		305			
t <sub>PLH</sub>	Propagation delay	A to B		13.8			μs
		B to A		16.6			
t <sub>FALL</sub>	A Port fall time	A-Port		160			ns
	B Port fall time	B-Port		170			
t <sub>RISE</sub>	A Port rise time	A-Port		305			ns
	B Port rise time	B-Port		28			
<b>VOLTAGE LEVEL SHIFTER – HPD LINES (x_A AND x_B PORTS) V<sub>CCA</sub> = 3.3 V</b>							
t <sub>PHL</sub>	Propagation delay	B to A	HPD channel enabled	14.2			μs
t <sub>PLH</sub>	Propagation delay	B to A		9.2			
t <sub>FALL</sub>	A Port fall time	A-Port		1.1			ns
t <sub>RISE</sub>	A Port rise time	A-Port		1.1			

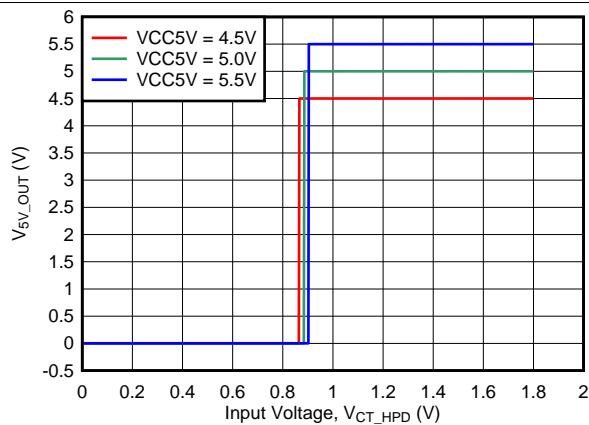
## 6.7 Typical Characteristics



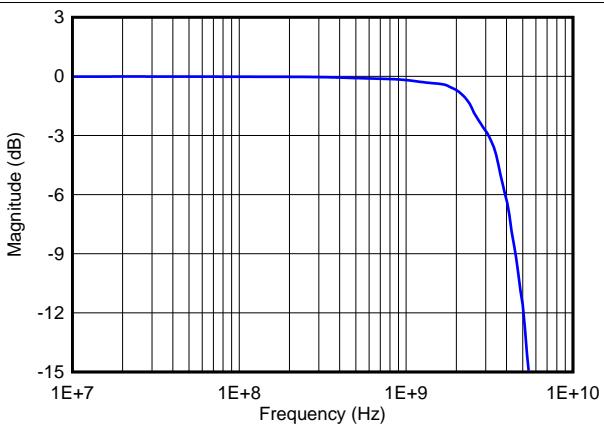
**Figure 1. IEC Clamping Waveform +8kv Contact**



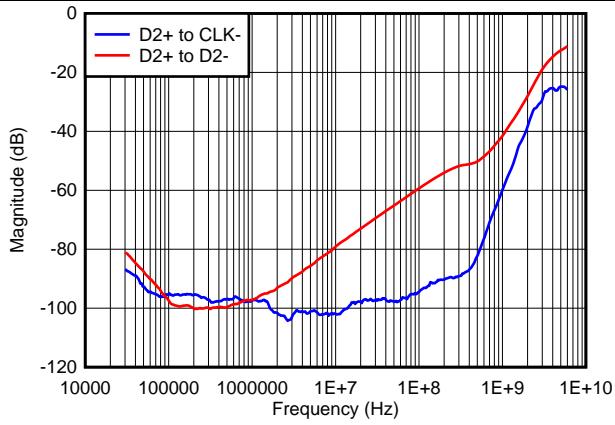
**Figure 2. IEC Clamping Waveform -8kv Contact**



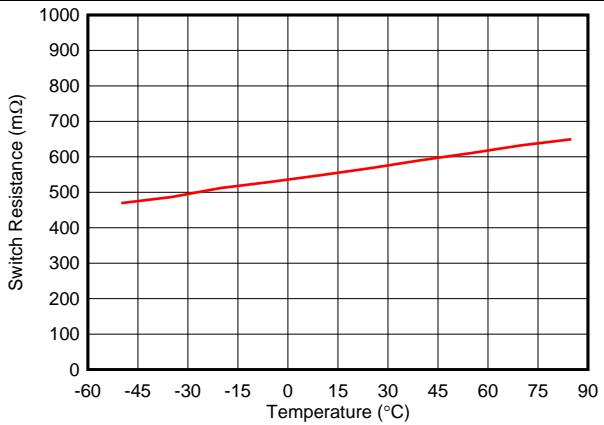
**Figure 3. CT\_HPD  $V_{IH}$**



**Figure 4. Insertion Loss, Data Line to GND**

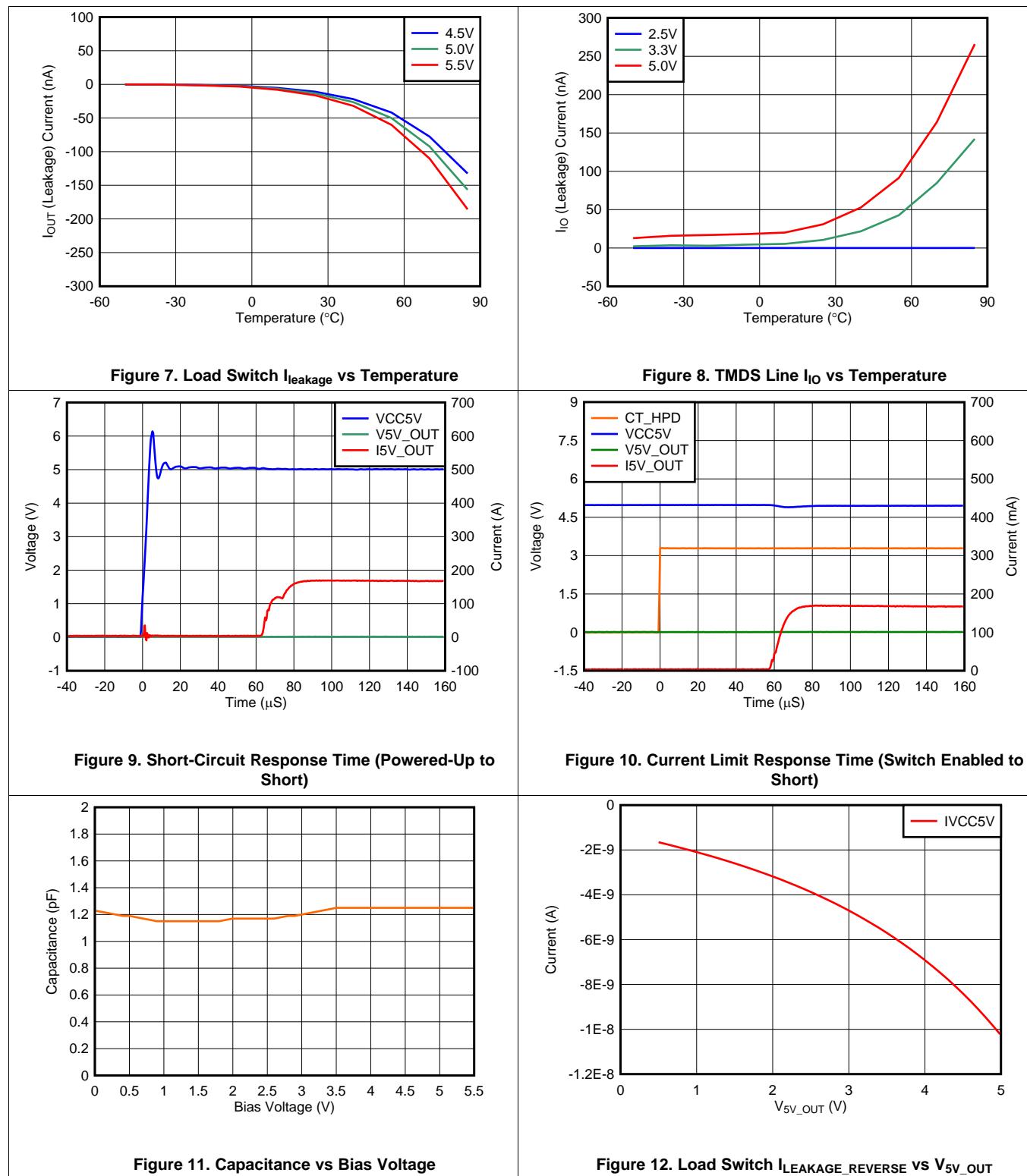


**Figure 5. Channel-to-Channel Crosstalk**



**Figure 6. Switch Resistance vs Temperature,  
 $I_{switch}$  at Approximately 55 mA**

## Typical Characteristics (continued)



## 7 Detailed Description

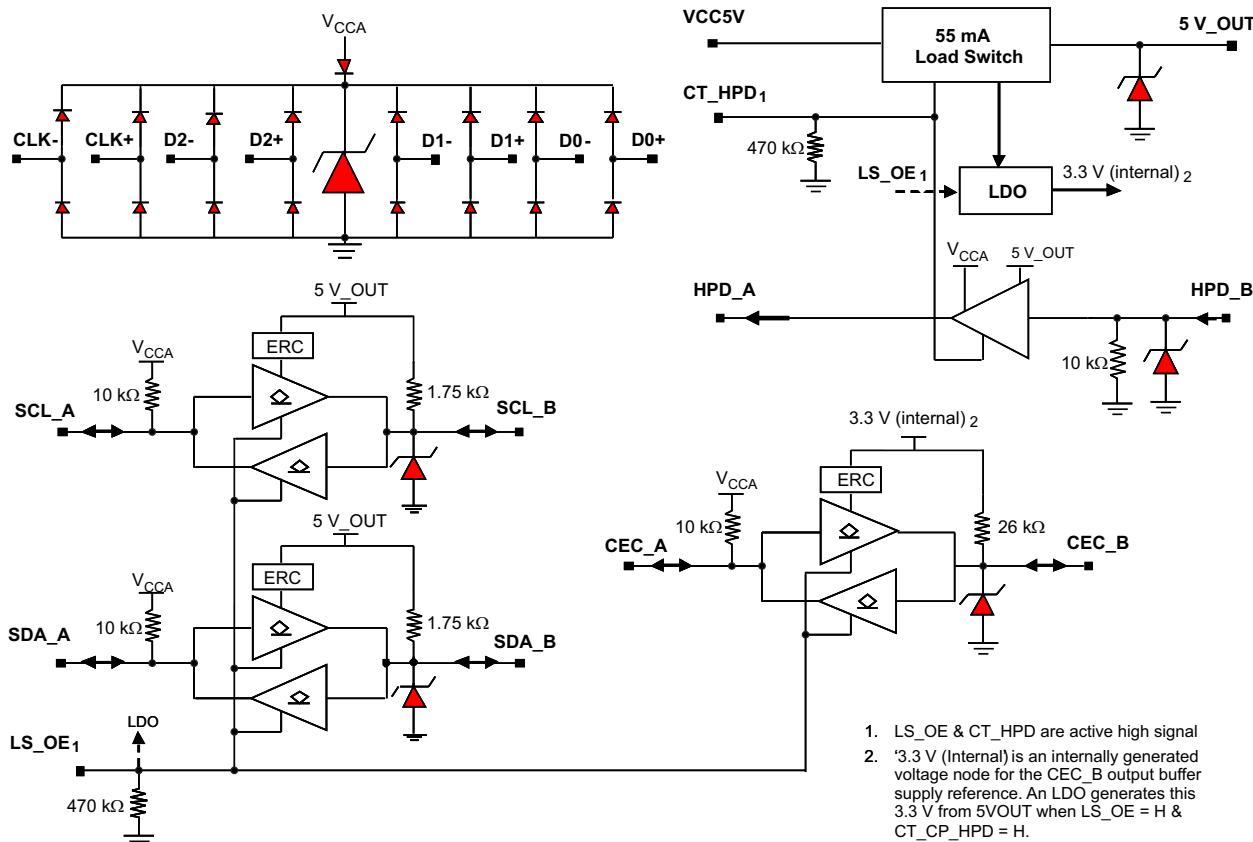
### 7.1 Overview

The TPD12S016 is a single-chip HDMI interface device with auto-direction sensing I<sup>2</sup>C voltage level shifting buffers, a load switch, and integrated high-speed ESD protection clamps. The device pin mapping matches the HDMI connector with four differential pairs and control lines. This device offers eight low-capacitance ESD clamps, allowing HDMI 1.4 data rates. The integrated ESD circuits provides matching between each differential signal pair, which allows an advantage over discrete ESD solutions where variations between ESD protection clamps degrade the differential signal quality. The TPD12S016 provides a current limited 5-V output (5V\_OUT) for sourcing the HDMI power line. The current limited 5-V output supplies up to 55 mA to the HDMI receiver. The control of 5V\_OUT and the hot plug detect (HPD) circuitry is independent of the LS\_OE control signal, and is controlled by the CT\_HPD pin. This independent CT\_HPD control enables the detection scheme (5V\_OUT and HPD) to be active before enabling the HDMI link. An internal 3.3 V node powers the CEC pin eliminating the need for a 3.3 V supply on board.

The TPD12S016 integrates all the external termination resistors at the HPD, CEC, SCL, and SDA lines. There are three non-inverting bidirectional voltage level translation (VLT) circuits for the SDA, SCL, and CEC lines. Each have a common power rail ( $V_{CCA}$ ) on the A side from 1.1 V to 3.6V. On the B side, the SCL\_B and SDA\_B each have an internal 1.75 kΩ pull up connected to the 5-V rail (5V\_OUT). The SCL and SDA pins meet the I<sup>2</sup>C specification and drive up to 750-pF capacitive loads exceeding the HDMI 1.4 specifications. The CEC\_B pin has an internal 27-kΩ pull up resistor to the internal 3.3-V supply rail. The HPD\_B port has a glitch filter to avoid false detection due to plug bouncing during the HDMI connector insertion.

The TPD12S016 offers a reverse current blocking feature at the 5V\_OUT pin. In the fault conditions, such as when two HDMI transmitters connect to the same HDMI cable, the TPD12S016 ensures that the system is safe from powering up through an external HDMI transmitter. The SCL\_B, SDA\_B, CEC\_B pins also feature reverse-current blocking when the system is powered off.

### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Conforms to HDMI Compliance Tests Without any External Components

The TPD12S016 has integrated pullup or pulldown resistors on the DDC, CEC, and HPD lines that conform to the HDMI 7.13 and 7.15 Compliance Tests without the designer needing to use any external components to TPD12S016.

### 7.3.2 IEC 61000-4-2 ESD Protection

In many cases, the core ICs, such as the scalar chipset, may not have robust ESD cells to sustain system-level ESD strikes. In these cases, the TPD12S016 provides the desired system-level ESD protection, such as the IEC 61000-4-2 Level 4 ESD protection of  $\pm 8\text{-kV}$  Contact rating by absorbing the energy associated with the ESD strike.

### 7.3.3 Supports HDMI 1.4 Data Rate

The high-speed TMDS pins of the TPD12S016 add only 1.0-pF (for PW package) or 1.2-pF (for RKT package) of capacitance to the TMDS lines. An Insertion Loss  $-3\text{ dB}$  point that is greater than 3 GHz provides enough bandwidth to pass HDMI 1.4 TMDS data rates.

### 7.3.4 Matches Class D and Class C Pin Mapping

The PW and RKT packages offer seamless layout routing options to eliminate the routing glitch for the differential signal pairs. The pin mapping follows the same order as the HDMI connector pin mapping.

### 7.3.5 8-Channel ESD Lines for Four Differential Pairs with Ultra-low Differential Capacitance Matching (0.05 pF)

Excellent intra-pair capacitance matching of 0.05 pF provides ultra low intra-pair skew, which allows an advantage over discrete ESD solutions where variations between ESD protection clamps can degrade the differential signal quality.

### 7.3.6 On-Chip Load Switch With 55-mA Current Limit Feature at the HDMI 5V\_OUT Pin

The TPD12S016 provides a current limited 5-V output (5V\_OUT) for sourcing the HDMI power line. The current limited 5-V output supplies up to 55 mA to the HDMI receiver. The control of 5V\_OUT and the HPD circuitry is independent of the LS\_OE control signal, and is controlled by the CT\_HPD pin. This independent CT\_HPD control enables the detection scheme (5V\_OUT and HPD) to be active before enabling the HDMI link.

### 7.3.7 Auto-direction Sensing I<sup>2</sup>C Level Shifter With One-Shot Circuit to Drive a Long HDMI Cable (750-pF Load)

The TPD12S016 contains three bidirectional open-drain buffers specifically designed to support up-translation/down-translation between the low voltage, V<sub>CCA</sub> side DDC-bus and the 5-V DDC-bus or 3.3-V CEC line. The HDMI cable side of the DDC lines incorporates rise-time accelerators to support a high capacitive load on the HDMI cable side. The rise time accelerators boost the cable side DDC signal independent of which side of the bus is releasing the signal.

### 7.3.8 Back-Drive Protection on HDMI Connector Side Ports

The TPD12S016 offers a reverse current blocking feature at the 5V\_OUT pin. In fault conditions, such as when two HDMI transmitters connect to the same HDMI cable, the TPD12S016 ensures that the system is safe from powering up through an external HDMI transmitter. The SCL\_B, SDA\_B, CEC\_B pins also feature reverse-current blocking when the system is powered off.

### 7.3.9 Integrated Pullup and Pulldown Resistors per HDMI Specification

The system is designed to work properly according to the HDMI 1.4 specification with no external pullup resistors on the DDC, CEC, and HPD lines.

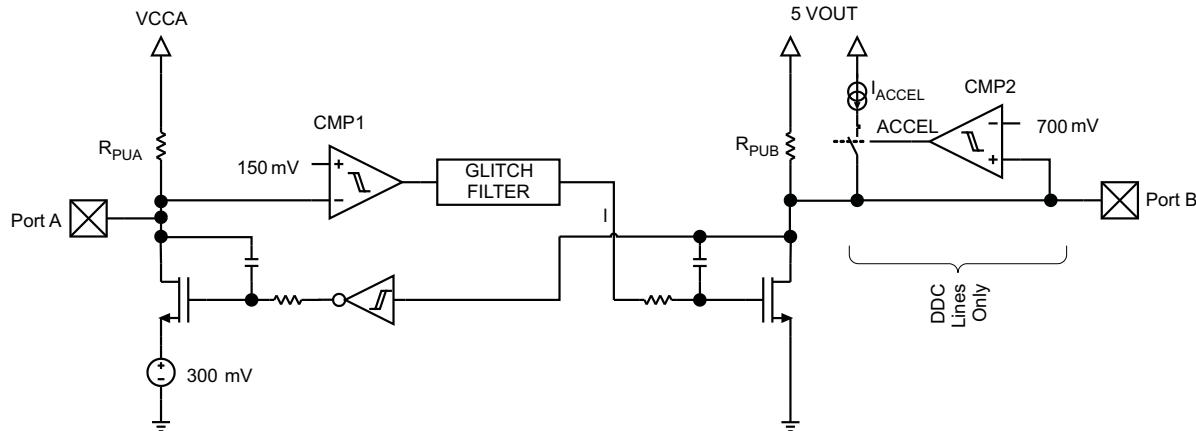
## Feature Description (continued)

### 7.3.10 Space Saving 24-Pin RKT Package and 24-TSSOP Package

When compared to discrete ESD solutions, the fully integrated port protection offered by TPD12S016 reduces the overall area required to fully protect an HDMI transmitter port.

### 7.3.11 DDC/CEC LEVEL SHIFT Circuit Operation

The TPD12S016 enables DDC translation from  $V_{CCA}$  (system side) voltage levels to 5-V (HDMI cable side) voltage levels without degradation of system performance. The TPD12S016 contains two bidirectional open-drain buffers specifically designed to support up-translation/down-translation between the low voltage,  $V_{CCA}$  side DDC-bus and the 5-V DDC-bus. The port B I/Os are over-voltage tolerant to 5.5 V, even when the device is un-powered. After power-up and with the LS\_OE and CT\_HPD pins HIGH, a LOW level on port A (below approximately  $V_{ILC} = 0.08 \times V_{CCA}$  V) turns the corresponding port B driver (either SDA or SCL) on and drives port B down to  $V_{OLB}$  V. When port A rises above approximately  $0.10 \times V_{CCA}$  V, the port B pulldown driver is turned off and the internal pullup resistor pulls the pin HIGH. When port B falls first and goes below  $0.3 \times 5$  VOUT V, a CMOS hysteresis input buffer detects the falling edge, turns on the port A driver, and pulls port A down to approximately  $V_{OLA} = 0.16 \times V_{CCA}$  V. The port B pulldown is not enabled unless the port A voltage goes below  $V_{ILC}$ . If the port A low voltage goes below  $V_{ILC}$ , the port B pulldown driver is enabled until port A rises above ( $V_{ILC} + \Delta V_{T-HYSTA}$ ), then port B, if not externally driven LOW, will continue to rise being pulled up by the internal pullup resistor.

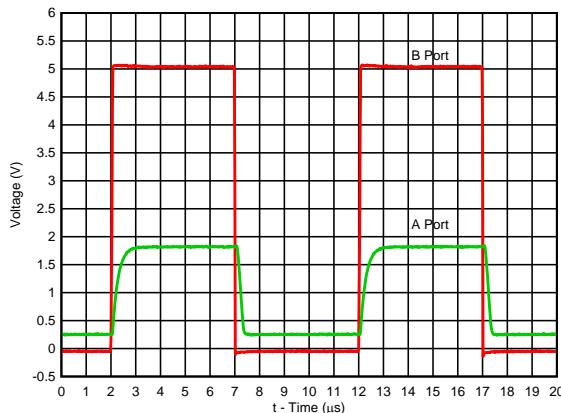


**Figure 13. DDC/CEC Level Shifter Block Diagram**

### 7.3.12 DDC/CEC Level Shifter Operational Notes For $V_{CCA} = 1.8$ V

- The threshold of CMP1 (see Figure 13) is approximately  $150 \text{ mV} \pm$  the 40 mV of total hysteresis.
- The comparator will trip for a falling waveform at approximately 130 mV.
- The comparator will trip for a rising waveform at approximately 170 mV.
- To be recognized as a zero, the level at Port A must first go below 130 mV ( $V_{ILC}$  in spec) and then stay below 170 mV ( $V_{ILA}$  in spec).
- To be recognized as a one, the level at A must first go above 170 mV and then stay above 130 mV.
- $V_{ILC}$  is set to 117 mV in Electrical Characteristics Table to give some margin to the 130 mV.
- $V_{ILA}$  is set to 148 mV in the *Electrical Characteristics* table to give some margin to the 170 mV.
- $V_{IHA}$  is set to 70% of  $V_{CCA}$  to be consistent with standard CMOS levels.

## Feature Description (continued)



**Figure 14. DDC Level Shifter Operation (B To A Direction)**

### 7.3.13 Rise-Time Accelerators

The HDMI cable side of the DDC lines incorporates rise-time accelerators to support high capacitive load (up to 750 pF) on the HDMI cable side. The rise time accelerators boost the cable side DDC signal independent of which side of the bus is releasing the signal.

### 7.3.14 Noise Considerations

Ground offset between the TPD12S016 ground and the ground of devices on port A of the TPD12S016 must be avoided. The reason for this cautionary remark is that a CMOS/NMOS open-drain capable of sinking 3 mA of current at 0.4 V will have an output resistance of 133 Ω or less ( $R = E / I$ ). Such a driver will share enough current with the port A output pulldown of the TPD12S016 to be seen as a LOW as long as the ground offset is zero. If the ground offset is greater than 0 V, then the driver resistance must be less. Since  $V_{ILC}$  can be as low as 90 mV at cold temperatures and the low end of the current distribution, the maximum ground offset should not exceed 50 mV. Bus repeaters that use an output offset are not interoperable with the port A of the TPD12S016 as their output LOW levels will not be recognized by the TPD12S016 as a LOW. If the TPD12S016 is placed in an application where the  $V_{IL}$  of port A of the TPD12S016 does not go below its  $V_{ILC}$  it will pull port B LOW initially when port A input transitions LOW but the port B will return HIGH, so it will not reproduce the port A input on port B. Such applications should be avoided. Port B is interoperable with all I<sup>2</sup>C-bus slaves, masters and repeaters.

### 7.3.15 Resistor Pullup Value Selection

The system is designed to work properly with no external pullup resistors on the DDC, CEC, and HPD lines.

## 7.4 Device Functional Modes

The LS\_OE and CT\_HPD are active-high enable pins. They control the TPD12S016 power saving options according to [Table 1](#).

**Table 1. Power Saving Options<sup>(1)</sup>**

LS_OE	CT_HPD	V <sub>CCA</sub>	V <sub>CC5V</sub>	A-SIDE PULL-UPS	DDC, B-SIDE PULL-UPS	CEC_B PULL-UPS	CEC LDO	LOAD SW AND HPD	DDC/CEC VLTs	ICCA TYP	ICC5V TYP	COMMENTS
L	L	1.8 V	5.0 V	Off	Off	Off	Off	Off	Off	1 μA	1 μA	Fully Disabled
L	H	1.8 V	5.0 V	On	On	Off	Off	On	Off	1 μA	30 μA	Load Switch on
H	L	1.8 V	5.0 V	Off	Off	Off	Off	Off	Off	1 μA	1 μA	Not a Valid State
H	H	1.8 V	5.0 V	On	On	On	On	On	On	13 μA	200 μA	Fully On
X	X	0 V	0 V	High-Z	High-Z	High-Z	Off	Off	Off	0	0	Power Down
X	X	1.8 V	0 V	High-Z	High-Z	High-Z	Off	Off	Off	0	0	Power Down
X	X	0 V	5.0 V	High-Z	High-Z	High-Z	Off	Off	Off	0	0	Power Down

(1) X = Don't Care, H = Signal High, and L = Signal Low

## 8 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

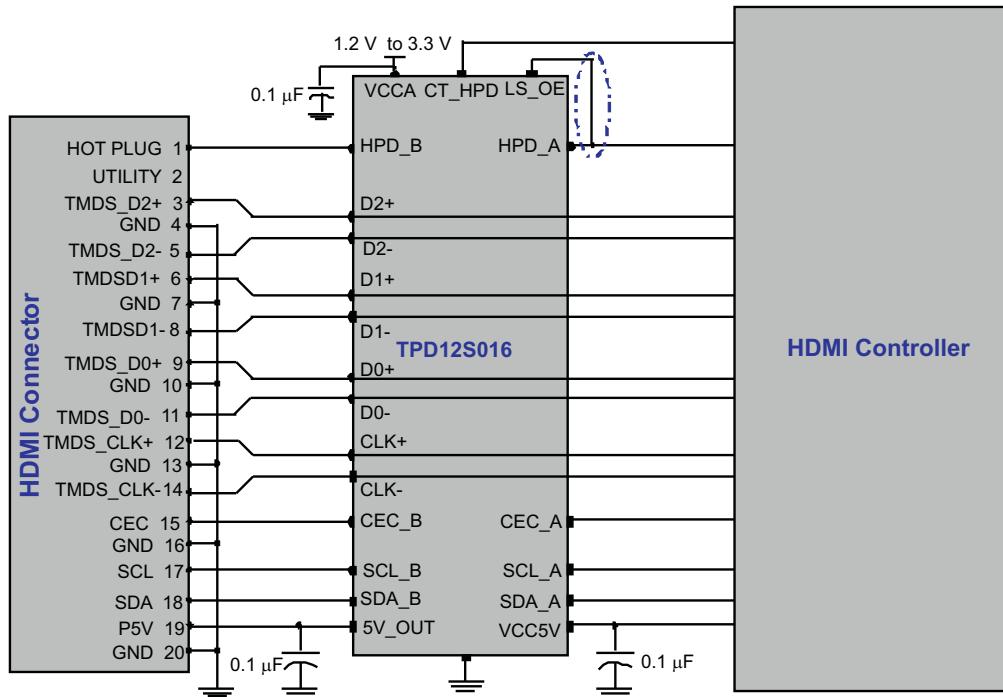
TPD12S016 provides IEC 61000-4-2 Level 4 Contact ESD rating to the HDMI 1.4 transmitter port. Buffered VLT's translate DDC and CEC channels bidirectionally. The system is designed to work properly with no external pullup resistors on the DDC, CEC, and HPD lines. The CEC line has an integrated 3.3-V rail, eliminating the need for a 3.3-V supply on board.

### 8.2 Typical Application

The TPD12S016 is placed as close as possible to the HDMI connector to provide voltage level translation, 5V\_OUT current limiting and overall ESD protection for the HDMI controller.

#### 8.2.1 Example 1: HDMI Controller Using One Control Line

In the example shown in [Figure 15](#), the HDMI driver chip is controlling the TPD12S016 through only one control line, CT\_HPD. In this mode the HPD\_A to LS\_OE pin are connected as shown in the oval dotted line of [Figure 15](#). To fully enable TPD12S016, set CT\_HPD above  $V_{IH}$ . To fully disable TPD12S016, set CT\_HPD below  $V_{IL}$ .



**Figure 15. TPD12S016 with an HDMI Controller Using One GPIO for HDMI Interface Control**

## Typical Application (continued)

### 8.2.1.1 Design Requirements

For this example, use the following table as input parameters:

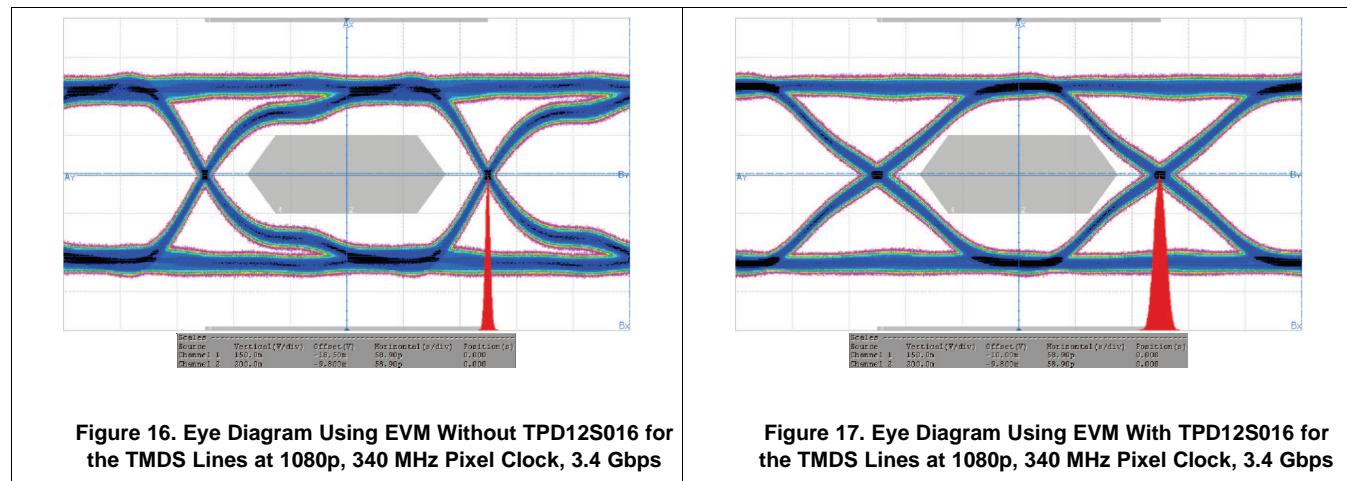
**Table 2. HDMI Controller Using One Control Line Design Parameters**

DESIGN PARAMETERS			EXAMPLE VALUE
Voltage on $V_{CCA}$			1.8 V
Voltage on $V_{CC5V}$			5.0 V
Drive CT_HPD low (disabled)			-0.5 V to 0.4 V
Drive CT_HPD high (enabled)			1.0 V to 1.8 V
Drive a logical 1	A to B	SCL and SDA	1.26 V to 1.8 V
		CEC	
Drive a logical 0	B to A	SCL and SDA	3.5 V to 5.0 V
		CEC	
Drive a logical 0	A to B	SCL and SDA	-0.5 V to 0.117 V
		CEC	
	B to A	SCL and SDA	-0.5 V to 1.5 V
		CEC	

### 8.2.1.2 Detailed Design Procedure

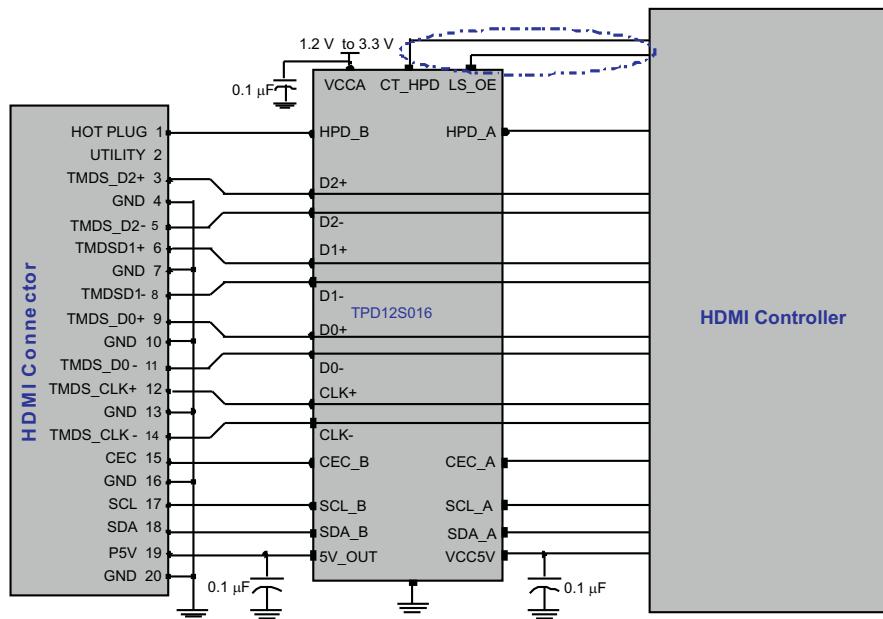
To begin the design process, the designer needs to know the  $V_{CC5V}$  voltage range and the logic level,  $V_{CCA}$ , voltage range.

### 8.2.1.3 Application Curves



### 8.2.2 Example 2: HDMI Controller Using CT\_HPD and LS\_OE

Some HDMI driver chips may have two GPIOs to control the HDMI interface chip. In this case a flexible power saving mode can be implemented. The load switch can be activated by CT\_HPD while the level shifters are inactive, using LS\_OE. This results in TPD12S016 drawing only approximately 30  $\mu$ A, a reduction of 170  $\mu$ A from being fully on. After a hot plug is detected, the HDMI controller can enable the rest of the HDMI interface chip using LS\_OE.



**Figure 18. TPD12S016 with an HDMI Controller Using Two GPIOs For HDMI Interface Control**

#### 8.2.2.1 Design Requirements

For this example, use [Table 3](#) for input parameters:

**Table 3. HDMI Controller Using CT\_HPD and LS\_OE Design Parameters**

DESIGN PARAMETERS			EXAMPLE VALUE
Voltage on $V_{CCA}$			3.3 V
Voltage on $V_{CC5V}$			5.0 V
Drive CT_HPD low (disabled)			-0.5 V to 0.4 V
Drive LS_OE low (disabled)			
Drive CT_HPD high (enabled)			1.0 V to 3.3 V
Drive LS_OE high (enabled)			
Drive a logical 1	A to B	SCL and SDA	2.31 V to 3.3 V
		CEC	
	B to A	SCL and SDA	3.5 V to 5.0 V
		CEC	2.31 V to 3.3 V
Drive a logical 0	A to B	SCL and SDA	-0.5 V to 0.214 V
		CEC	
	B to A	SCL and SDA	-0.5 V to 1.5 V
		CEC	-0.5 V to 0.99 V

### 8.2.2.2 Detailed Design Procedure

To begin the design process, the designer needs to know the  $V_{CC5V}$  voltage range and the logic level,  $V_{CCA}$ , voltage range.

### 8.2.2.3 Application Curves

Refer to [Application Curves](#) for related application curves.

## 9 Power Supply Recommendations

TPD12S016 has two power input pins:  $V_{CC5V}$  and  $V_{CCA}$ . It can operate normally with  $V_{CC5V}$  between 4.5 V and 5.5 V; and  $V_{CCA}$  between 1.1 V and 3.6 V. Thus, the power supply (with a ripple of  $V_{RIPPLE}$ ) requirement for TPD12S016 for  $V_{CC5V}$  is between 4.5 V +  $V_{RIPPLE}$  and 5.5 V –  $V_{RIPPLE}$ ; and for  $V_{CCA}$  it is between 1.1 V +  $V_{RIPPLE}$  and 3.6 V –  $V_{RIPPLE}$ .

## 10 Layout

### 10.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
  - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures. Therefore, the PCB designer needs to minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Avoid using VIAs between the connector and an I/O protection pin on TPD12S016.
- Avoid 90° turns in traces.
  - Electric fields tend to build up on corners, increasing EMI coupling.
- Minimize impedance on the path to GND for maximum ESD dissipation.
- The capacitors on  $V_{BUS}$  and  $V_{OTG\_IN}$  should be placed close to their respective pins on TPD12S016.

### 10.2 Layout Examples

#### 10.2.1 TPD12S016RKT

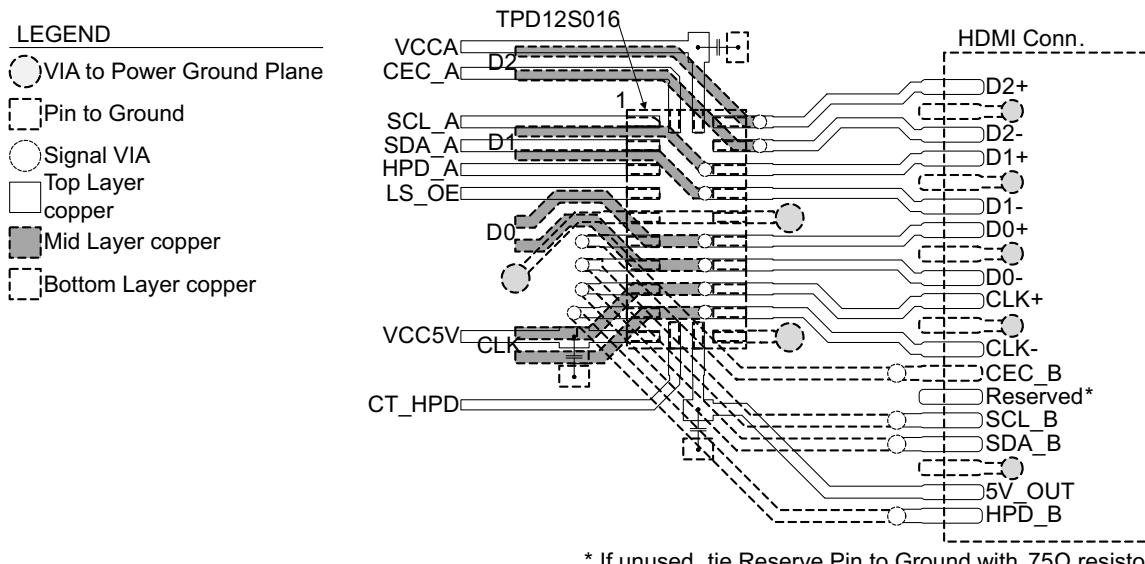
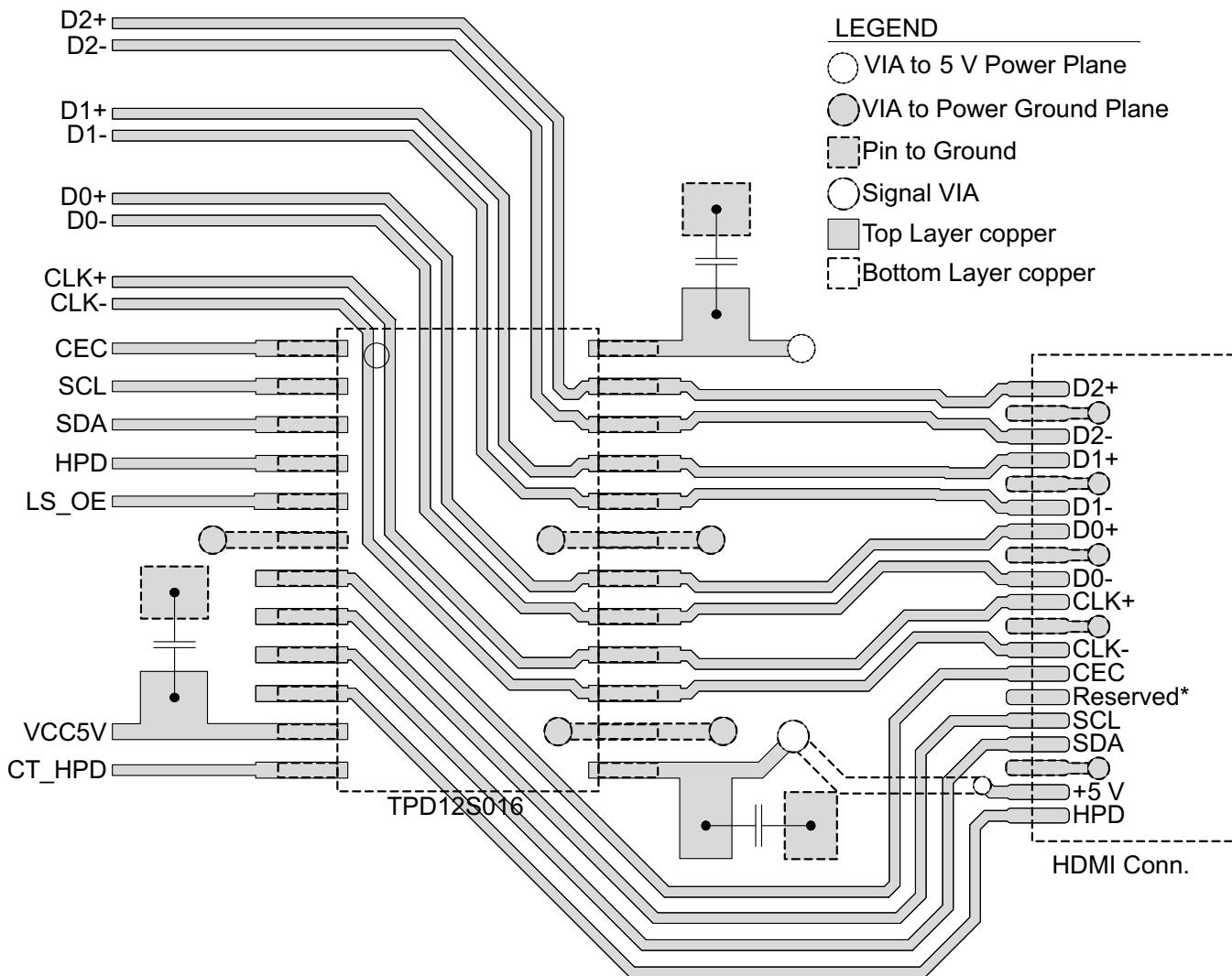


Figure 19. TPD12S016RKT Layout Example

## Layout Examples (continued)

Routing with TPD12S016RKT requires three layers. Vias are an integral part of layout for such a design. Proper placement of vias can eliminate exposing the system unnecessarily to an ESD event. The example shown above routes the TMDS lines directly from the connector to the protection pins *before* using vias to an internal layer. This helps promote ESD energy dissipation at the TPD12S016 protection pins. Note that while there is a via between the connector and the DDC/CEC/HPD lines, the traces terminate at the protection pins, leaving no other path for ESD energy to dissipate except at the TPD12S016 protection pins. All ground pins should have a large via near them connecting to as many internal and external ground planes as possible to reduce any impedance between TPD12S016 and ground. Tenting of VIAs near to SMD pads should be done to eliminate any solder-wicking during PCB assembly.

### 10.2.2 TPD12S016PW



\* If unused, tie Reserve Pin to Ground with  $75\Omega$  resistor

**Figure 20. TPD12S016PW Layout Example**

The TPD12S016PW can be routed on a single layer. HDMI connector pin matching has been arranged to allow for a flow through routing style. All ground pins should have a large via near them connecting to as many internal and external ground planes as possible to reduce any impedance between TPD12S016 and ground. Tenting of vias near to SMD pads should be done to eliminate any solder-wicking during PCB assembly.

## 11 器件和文档支持

### 11.1 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.2 商标

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### 11.3 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

### 11.4 Glossary

[SLYZ022 — TI Glossary.](#)

This glossary lists and explains terms, acronyms, and definitions.

## 12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPD12S016PWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	PN016	<span style="background-color: red; color: white;">Samples</span>
TPD12S016RKTR	ACTIVE	UQFN	RKT	24	3000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	PN016	<span style="background-color: red; color: white;">Samples</span>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

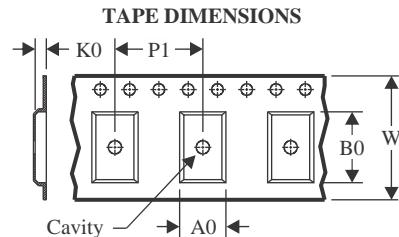
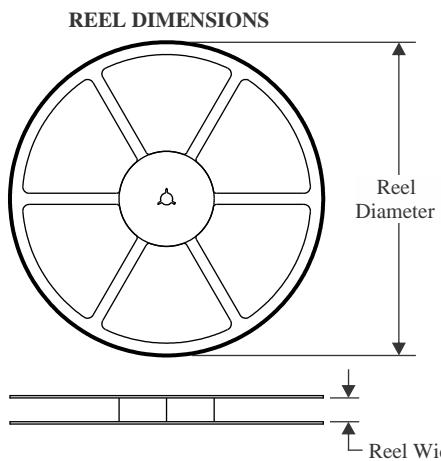
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

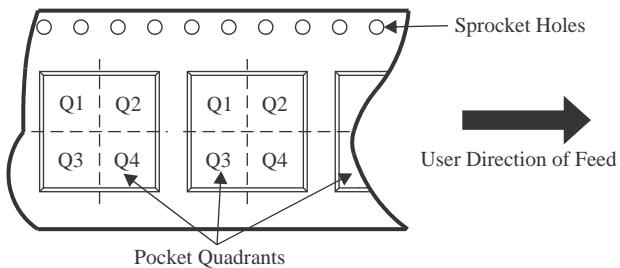
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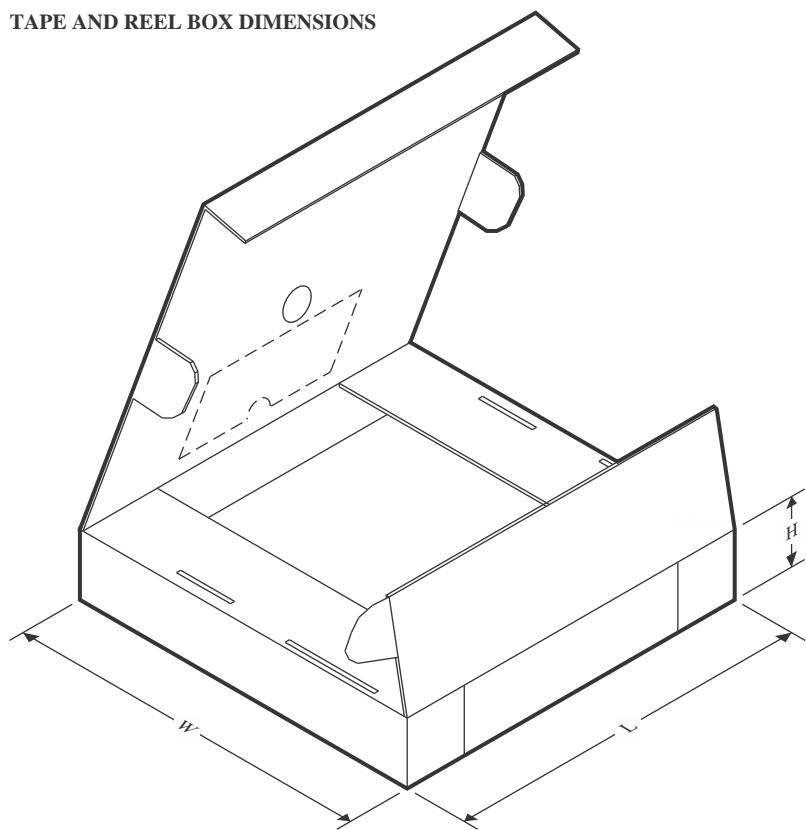
**TAPE AND REEL INFORMATION**

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD12S016PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
TPD12S016RKTR	UQFN	RKT	24	3000	177.8	12.4	2.21	4.22	0.81	4.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

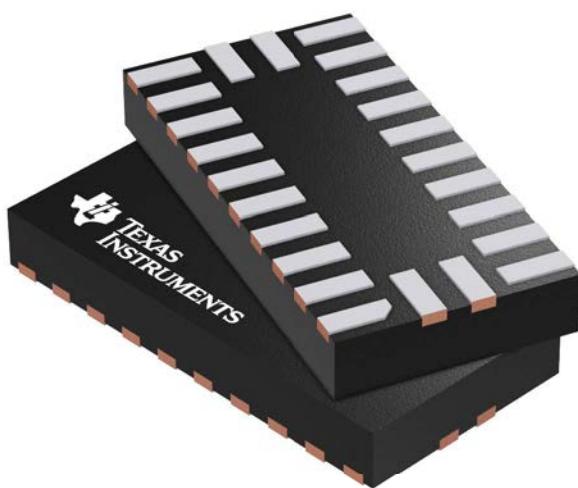
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD12S016PWR	TSSOP	PW	24	2000	356.0	356.0	35.0
TPD12S016RKTR	UQFN	RKT	24	3000	183.0	183.0	20.0

## GENERIC PACKAGE VIEW

RKT 24

**UQFN - 0.55 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4211396/B

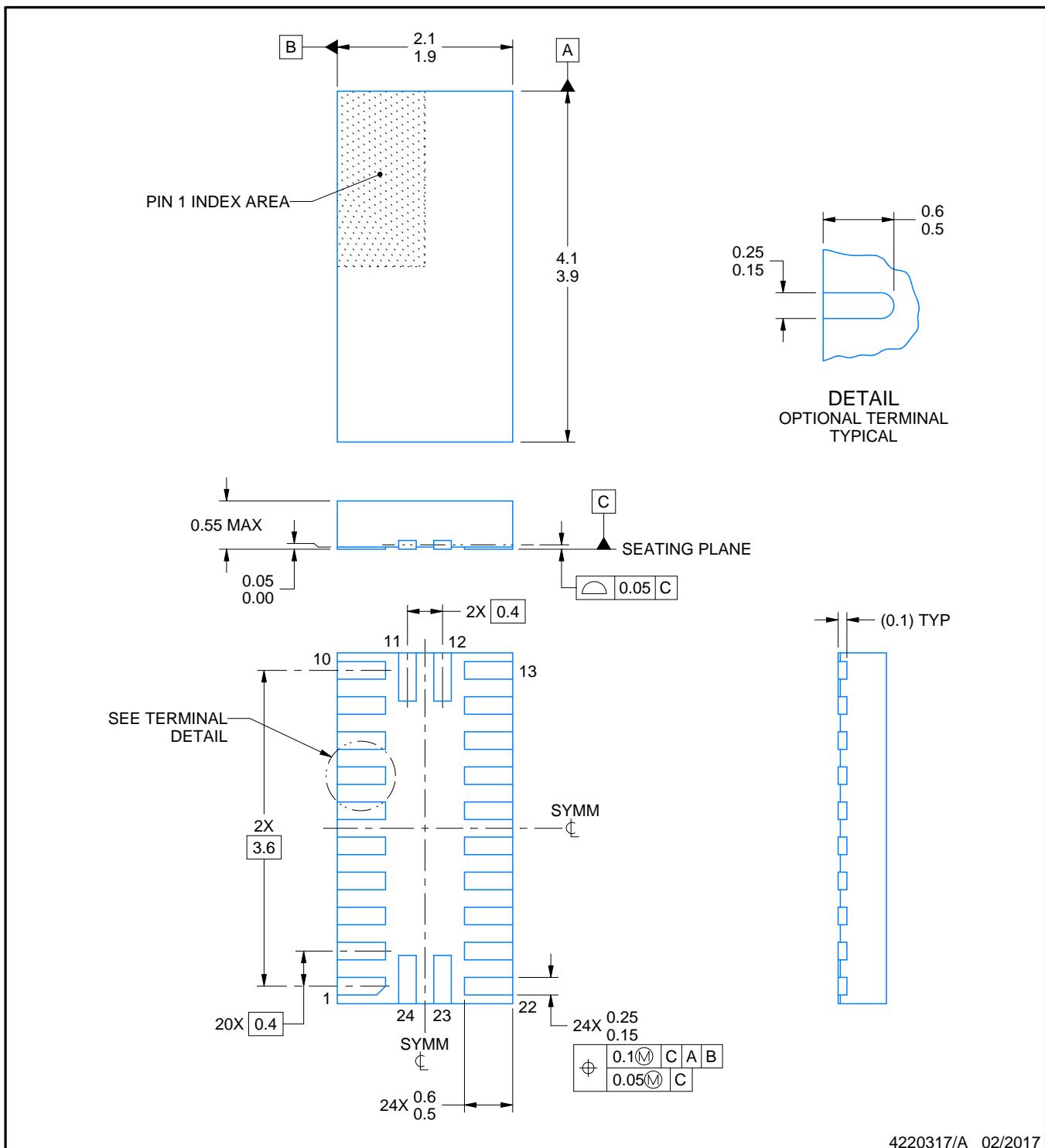
# PACKAGE OUTLINE

RKT0024A



UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



## NOTES:

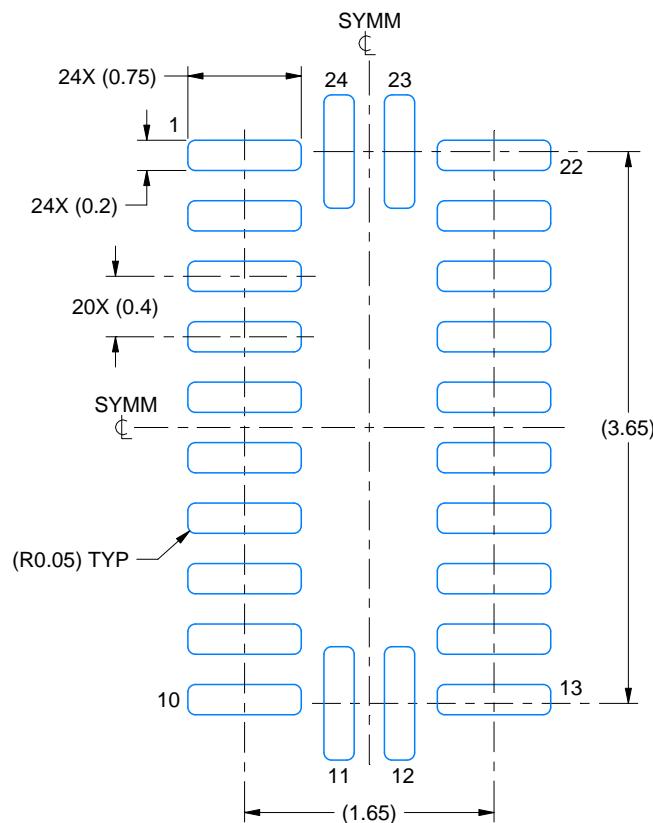
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

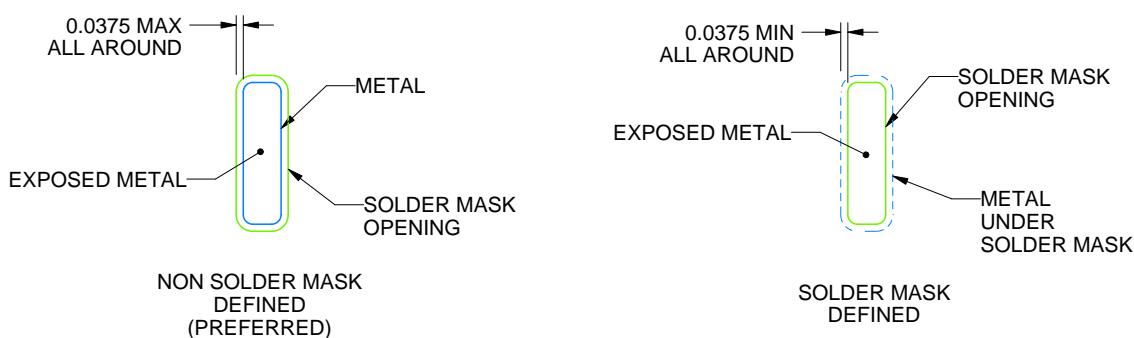
RKT0024A

UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:20X



SOLDER MASK DETAILS  
NOT TO SCALE

4220317/A 02/2017

NOTES: (continued)

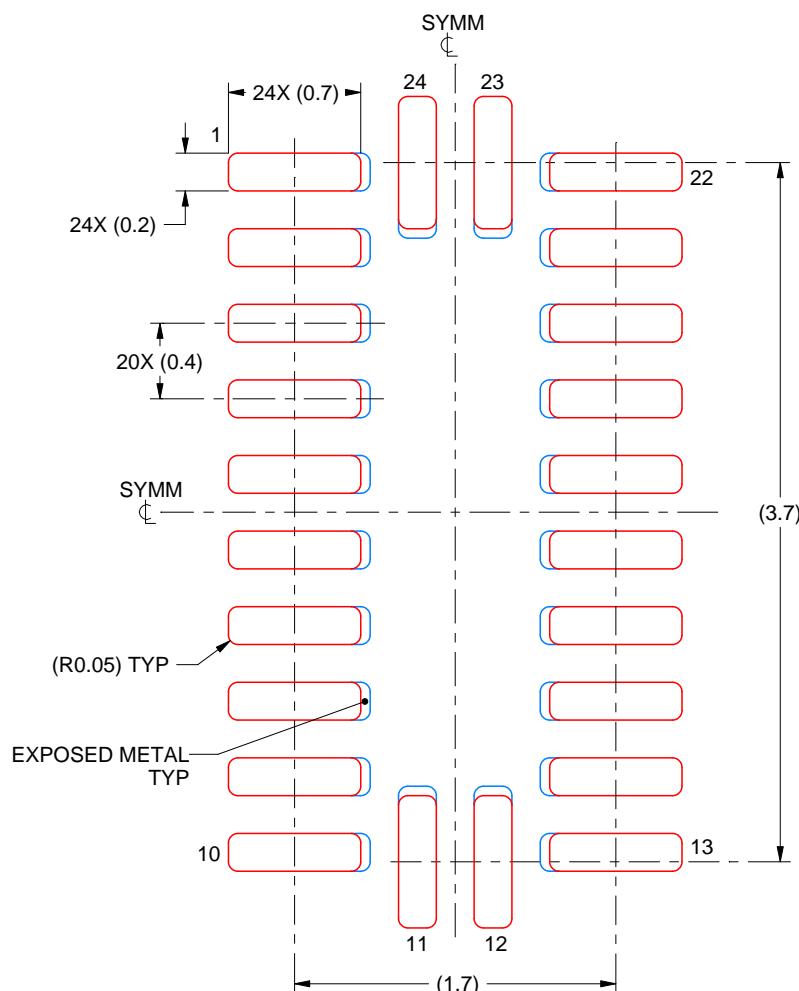
3. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).

# EXAMPLE STENCIL DESIGN

RKT0024A

UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICKNESS  
SCALE:25X

4220317/A 02/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

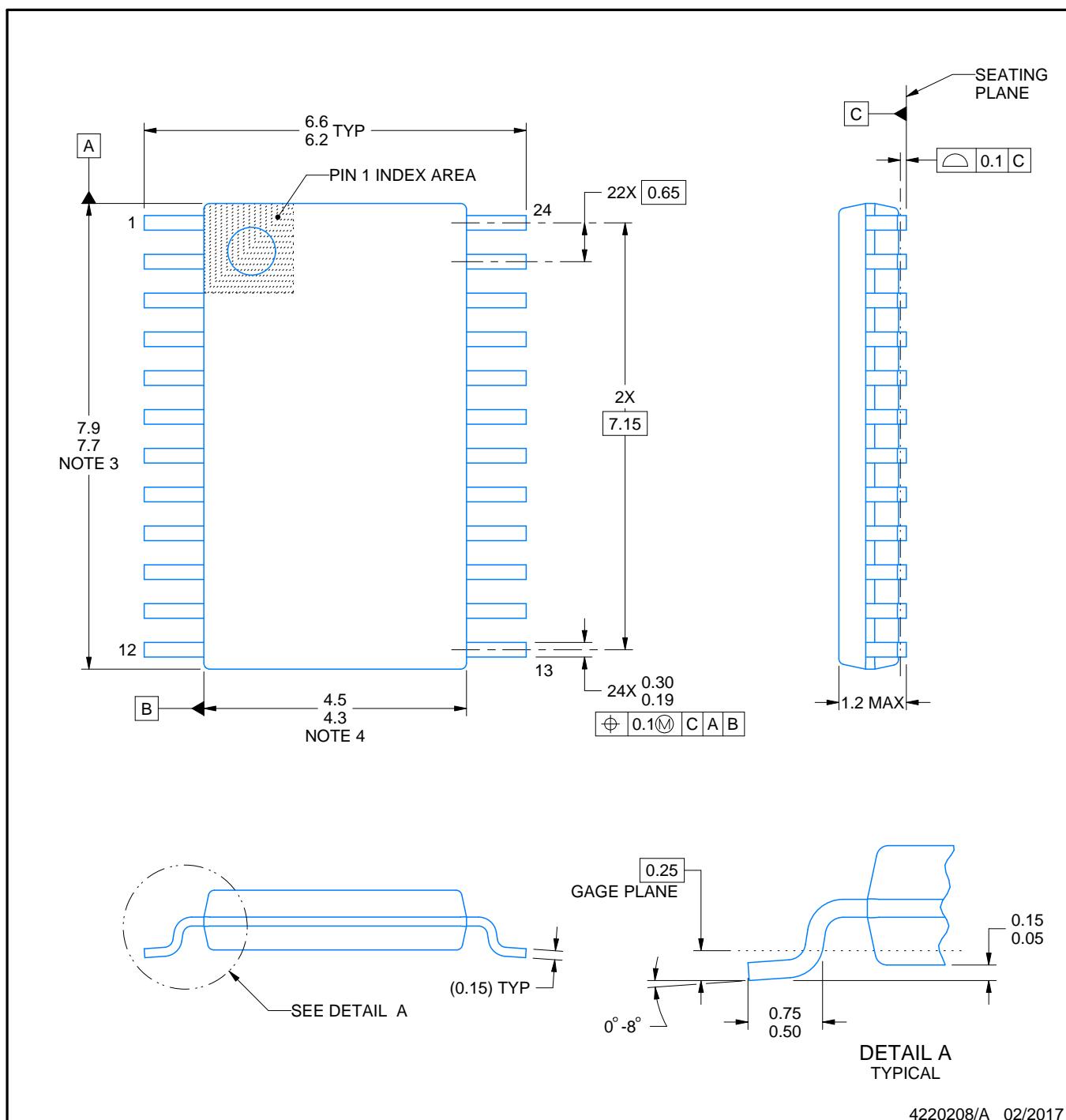
# PACKAGE OUTLINE

PW0024A



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

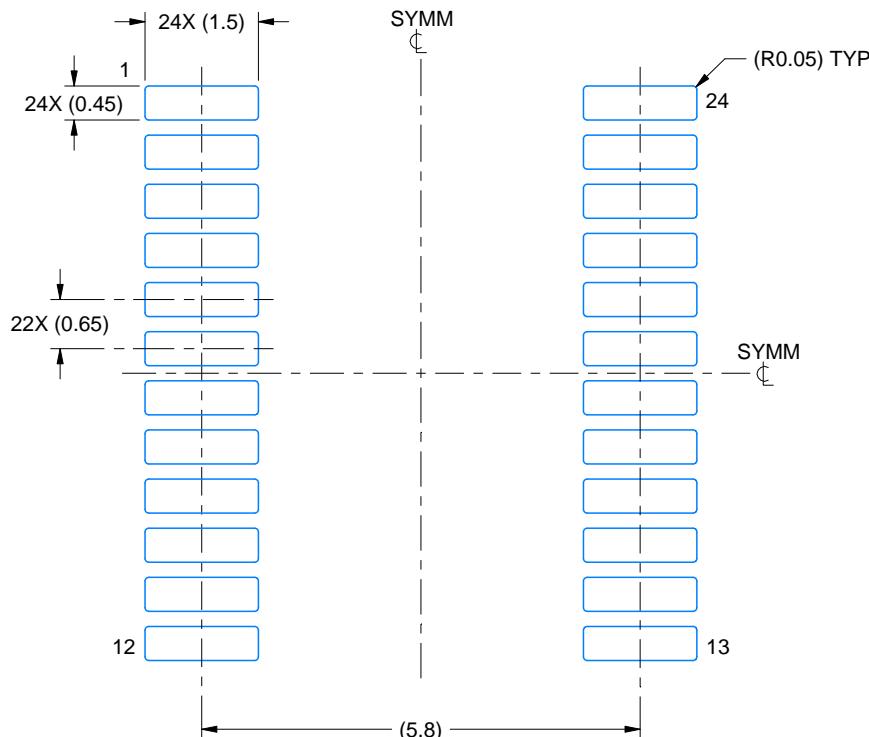
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

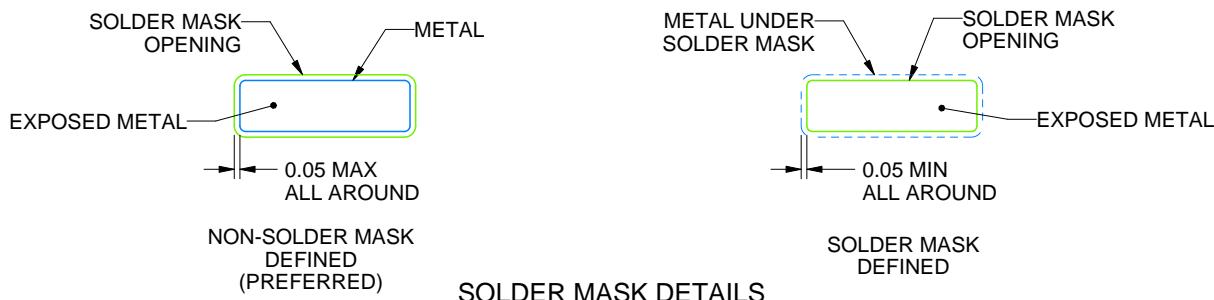
PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220208/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

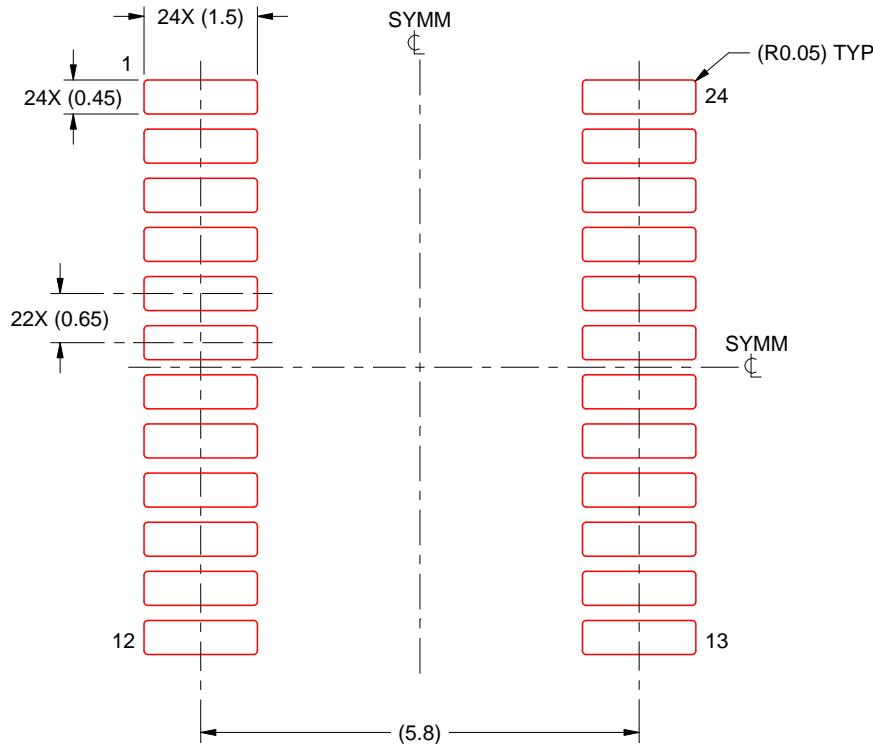
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220208/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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